Revision. 3

MOS FET

FC8V22040L

Panasonic

FC8V22040L

Gate Resistor installed Dual N-Channel MOS Type

For lithium-ion secondary battery protection circuit

■ Features

- Low drain-source On-state Resistance: RDS(on)typ. = $10.5 \text{ m}\Omega(\text{VGS} = 4.5 \text{ V})$
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 40
- Basic Part Number : Dual Nch MOS 24V (Drain Common type)

■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Absolute Maximum Ratings Ta = 25 °C Tr.1,Tr.2

Parameter Symbol Rating Unit

Drain-source Voltage VDS 24 V

EET 1 Cate source Voltage VGS +12 V

FET1 FET2	Drain-source Voltage	VDS	24	V	
	Gate-source Voltage	VGS	±12	V	
	Drain Current	ID	8	Α	
	Drain Current (Pulsed)	IDp	48	Α	
Overall	Power Dissipation	PD1 *1	1.0		
		PD2 *1,2	1.2	W	
		PD3 *3	0.4		
	Channel Temperature	Tch	150	°C	
	Operating Ambient Temperature	Topr	-40 to + 85	°C	
	Storage Temperature Range	Tstg	-55 to +150	°C	

Note) *1 Glass epoxy board: 25.4 mm × 25.4 mm × 0.8 mm Copper foil of the drain portion should have a area of 300 mm² or more PD absolute maximum rating without a heat shink: 400 mW

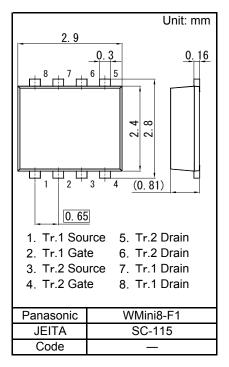
*2 t = 10 s

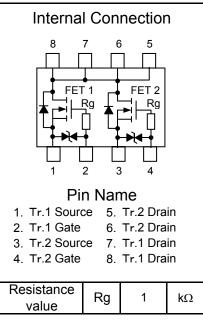
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Revised

*3 Stand-alone (without the board)





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■ Electrical Characteristics Ta = 25°C ± 3°C Tr.1,Tr.2

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source surrender voltage	VDSS	ID = 1.0 mA, VGS = 0	24			V
Drain-source cutoff current	IDSS	VDS = 24 V, VGS = 0			1.0	μΑ
Gate-source cutoff current	IGSS	VGS = ±8.0 V, VDS = 0			±10	μΑ
Gate threshold voltage	Vth	ID = 1.0 mA, VDS = 10 V	0.40	0.85	1.50	V
	RDS(ON)1	ID = 4.0 A, VGS = 4.5 V	7.0	10.5	15	mΩ
Drain-source ON resistance	RDS(ON)2	ID = 4.0 A, VGS = 4.0 V	7.2	11.0	16	mΩ
Diain-source On resistance	RDS(ON)3	ID = 4.0 A, VGS = 3.1 V	7.5	12.0	18	mΩ
	RDS(ON)4	ID = 4.0 A, VGS = 2.5 V	8.0	13.5	20	mΩ
Turn-on delay time *1	td(on)	VDD = 10 V, VGS = 0 V to 4 V		0.6		μs
Rise time *1	tr	ID = 4.0 A		1.5		μs
Turn-off delay time *1	td(off)	VDD = 10 V, VGS = 4 V to 0 V		4.4		μs
Fall time *1	tf	ID = 4.0 A		2.8		μs
Source to Drain Diode Forward Voltage	VSD	IS = 4.0 A, VGS = 0 V		0.8	1.2	V

Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors. Note)

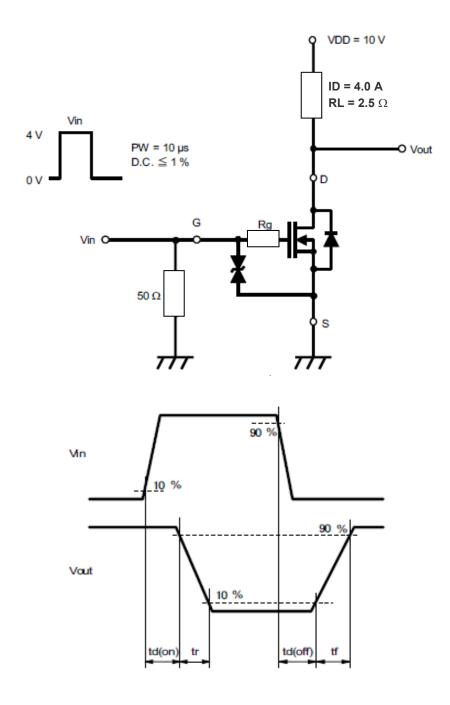
^{2. *1} Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time

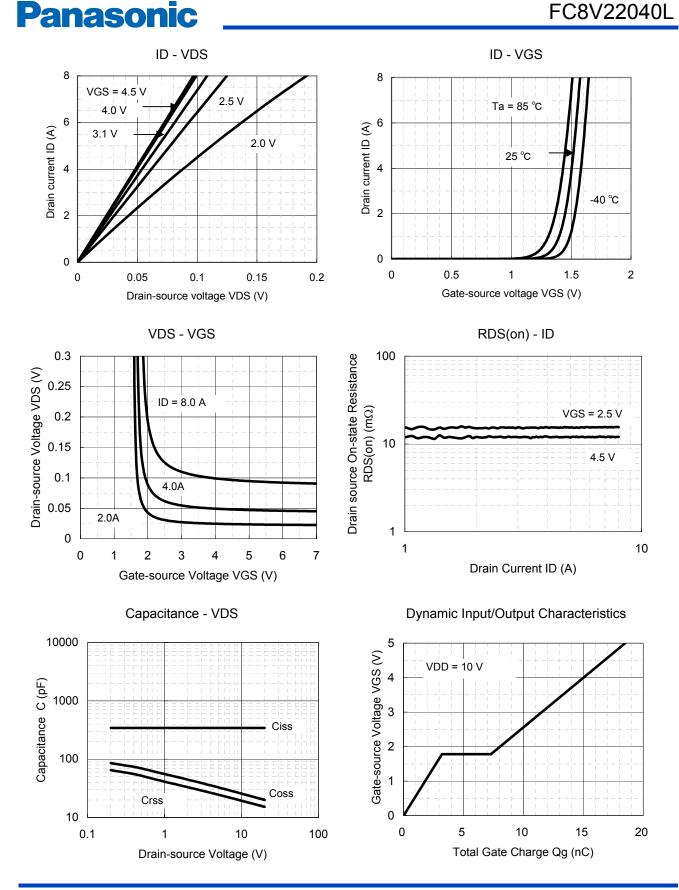
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*1 Measurement circuit for Turn-on Delay Time/Rise Time/Turn-off Delay Time/Fall Time



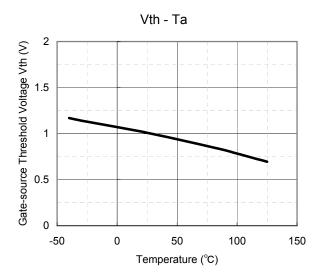


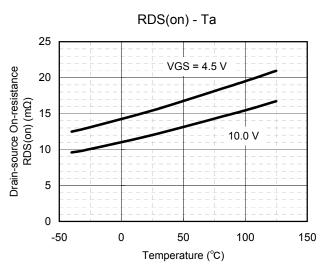
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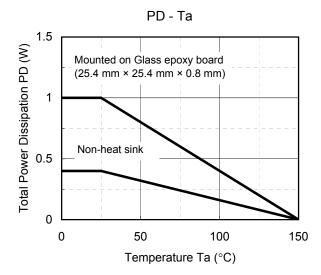
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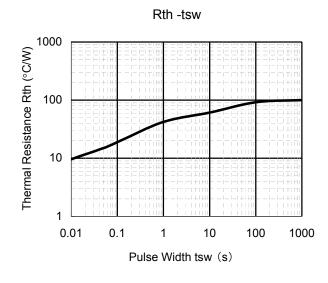
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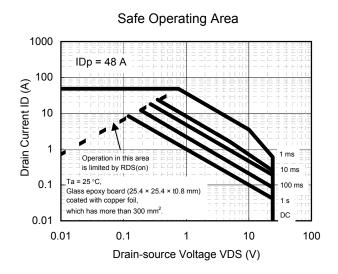
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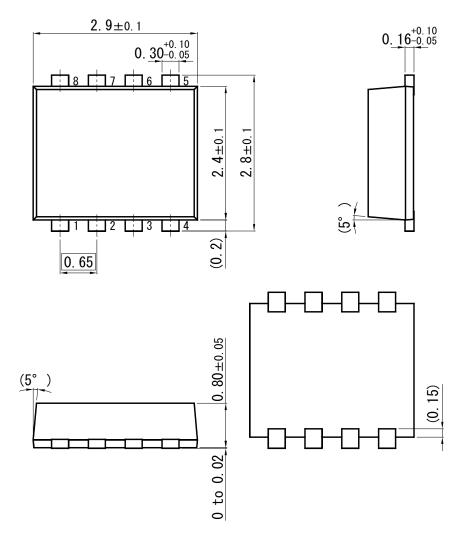
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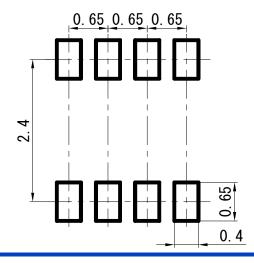
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WMini8-F1

Unit: mm



■ Land Pattern (Reference) (Unit : mm)



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